

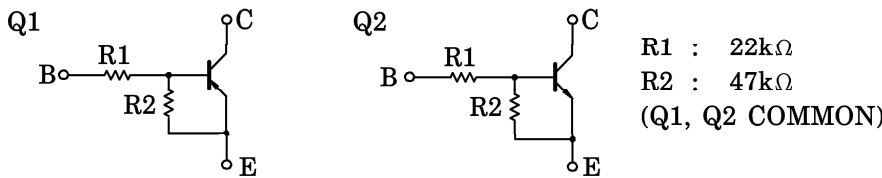
TOSHIBA TRANSISTOR
 SILICON PNP EPITAXIAL TYPE (PCT PROCESS) SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

RN4608

SWITCHING, INVERTER CIRCUIT, INTERFACE CIRCUIT
 AND DRIVER CIRCUIT APPLICATIONS.

- Including Two Devices in SM6 (Super Mini Type with 6 leads)
- With Built-in Bias Resistors
- Simplify Circuit Design
- Reduce a Quantity of Parts and Manufacturing Process

EQUIVALENT CIRCUIT AND BIAS RESISTOR VALUES



Q1 MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CB0}	-50	V
Collector-Emitter Voltage	V _{CEO}	-50	V
Emitter-Base Voltage	V _{EBO}	-7	V
Collector Current	I _C	-100	mA

Q2 MAXIMUM RATINGS (Ta = 25°C)

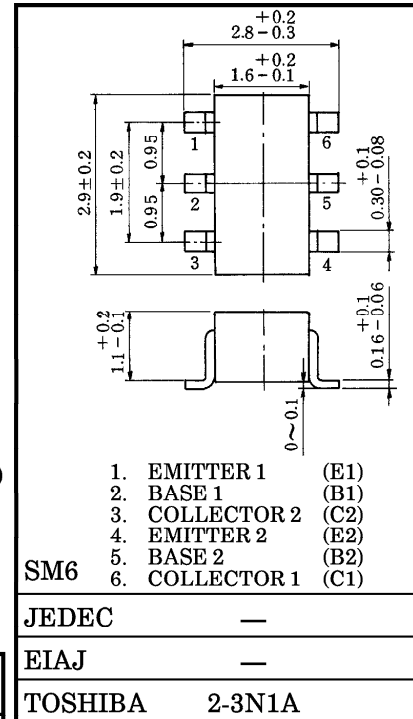
CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CB0}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Collector Current	I _C	100	mA

Q1, Q2 COMMON MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector Power Dissipation	P _C *	300	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-55~150	°C

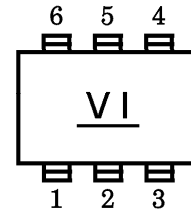
* : Total Rating

Unit in mm

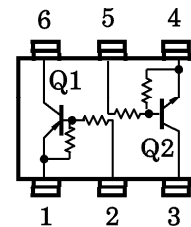


Weight : 0.015g

MARKING



EQUIVALENT CIRCUIT (TOP VIEW)



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Q1 ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
	I_{CEO}	$V_{CE} = -50V, I_B = 0$	—	—	-500	
Emitter Cut-off Current	I_{EBO}	$V_{EB} = -7V, I_C = 0$	-0.078	—	-0.145	mA
DC Current Gain	h_{FE}	$V_{CE} = -5V, I_C = -10mA$	80	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -5mA, I_B = -0.25mA$	—	-0.1	-0.3	V
Input Voltage (ON)	$V_{I(ON)}$	$V_{CE} = -0.2V, I_C = -5mA$	-1.0	—	-2.6	V
Input Voltage (OFF)	$V_{I(OFF)}$	$V_{CE} = -5V, I_C = -0.1mA$	-0.6	—	-1.16	V
Transition Frequency	f_T	$V_{CE} = -10V, I_C = -5mA$	—	200	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = -10V, I_E = 0, f = 1MHz$	—	3	6	pF

Q2 ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB} = 50V, I_E = 0$	—	—	100	nA
	I_{CEO}	$V_{CE} = 50V, I_B = 0$	—	—	500	
Emitter Cut-off Current	I_{EBO}	$V_{EB} = 7V, I_C = 0$	0.078	—	0.145	mA
DC Current Gain	h_{FE}	$V_{CE} = 5V, I_C = 10mA$	80	—	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 5mA, I_B = 0.25mA$	—	0.1	0.3	V
Input Voltage (ON)	$V_{I(ON)}$	$V_{CE} = 0.2V, I_C = 5mA$	1.0	—	2.6	V
Input Voltage (OFF)	$V_{I(OFF)}$	$V_{CE} = 5V, I_C = 0.1mA$	0.6	—	11.6	V
Transition Frequency	f_T	$V_{CE} = 10V, I_C = 5mA$	—	250	—	MHz
Collector Output Capacitance	C_{ob}	$V_{CB} = 10V, I_E = 0, f = 1MHz$	—	3	6	pF

Q1, Q2 COMMON ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Resistor	R1	—	15.4	22	28.6	kΩ
Resistor Ratio	R1/R2	—	0.421	0.468	0.515	

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